

20A 3Quadrants TRIACs

Product Summary

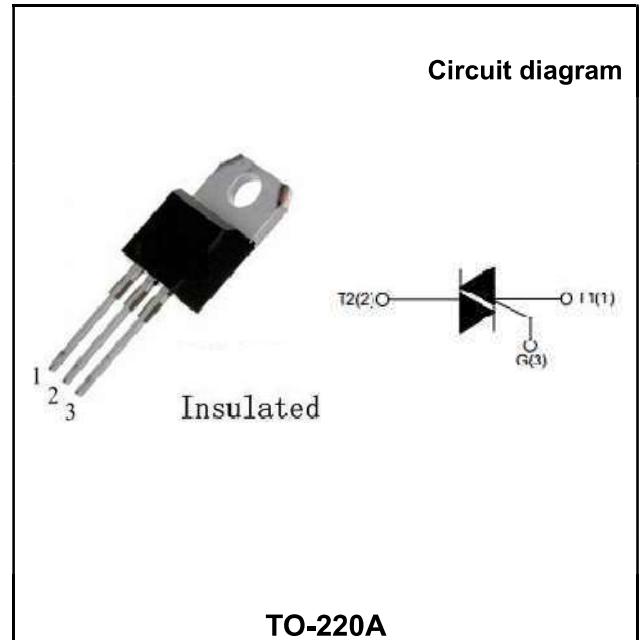
Symbol	Value	Unit
$I_{T(AV)}$	20	A
$V_{DRM} V_{RRM}$	600/800	V
V_{TM}	1.55	V

Features

With high ability to withstand the shock loading of large current, Provide high dv/dt rate with strong resistance to electromagnetic interference

Application

Power charger, T-tools, massager, solid staterelay, AC Motor speed regulation and so on.



Order Information

Part Number	Package	Marking	packing	packing Quantity
BTA20	TO-220A	BTA20 XXXX	Box	1000PCS/Box

Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value		Unit
Repetitive peak off-state voltage	V_{DRM}	600/800		V
Repetitive peak reverse voltage	V_{RRM}	600/800		V
RMS on-state current	$I_{T(RMS)}$	20		A
Non repetitive surge peak on-state current (full cycle, F=50Hz)	I_{TSM}	210		A
I^2t value for fusing (tp=10ms)	I^2t	200		A^2s
Critical rate of rise of on-state current ($ IG = 2 \times GT $)	dI/dt	I - II - III	50	A/us
Peak gate current	I_{GM}	4		A
Average gate power dissipation	$P_G(AV)$	1		W
Junction Temperature	T_J	-40~+125		°C
Storage Temperature	T_{STG}	-40 ~+150		°C

Electrical characteristics (TA=25°C, unless otherwise noted)

Parameter	Symbol	Test Condition	Value		Unit
			CW	BW	
Gate trigger current	I _{GT}	V _D =12V, RL=33Ω , T _j =25°C , Fig.6	I - II - III	≤35	≤50 mA
Gate trigger voltage	V _{GT}		I - II - III	≤1.3 V	
Gate non-trigger voltage	V _{GD}	V _D =V _{DRM} , T _j =125°C		≥0.2 V	
Holding current	I _H	I _T =500mA, Fig. 6		≤50	≤75 mA
latching current	I _L	IG=1.2IGT, Fig. 6	I - III	≤50	≤70 mA
			II	≤80	≤90 mA
Critical-rate of rise of commutation voltage	dV _D /dt	V _D =2/3V _{DRM} , T _j =125°C		≥500	≥1000 V/us

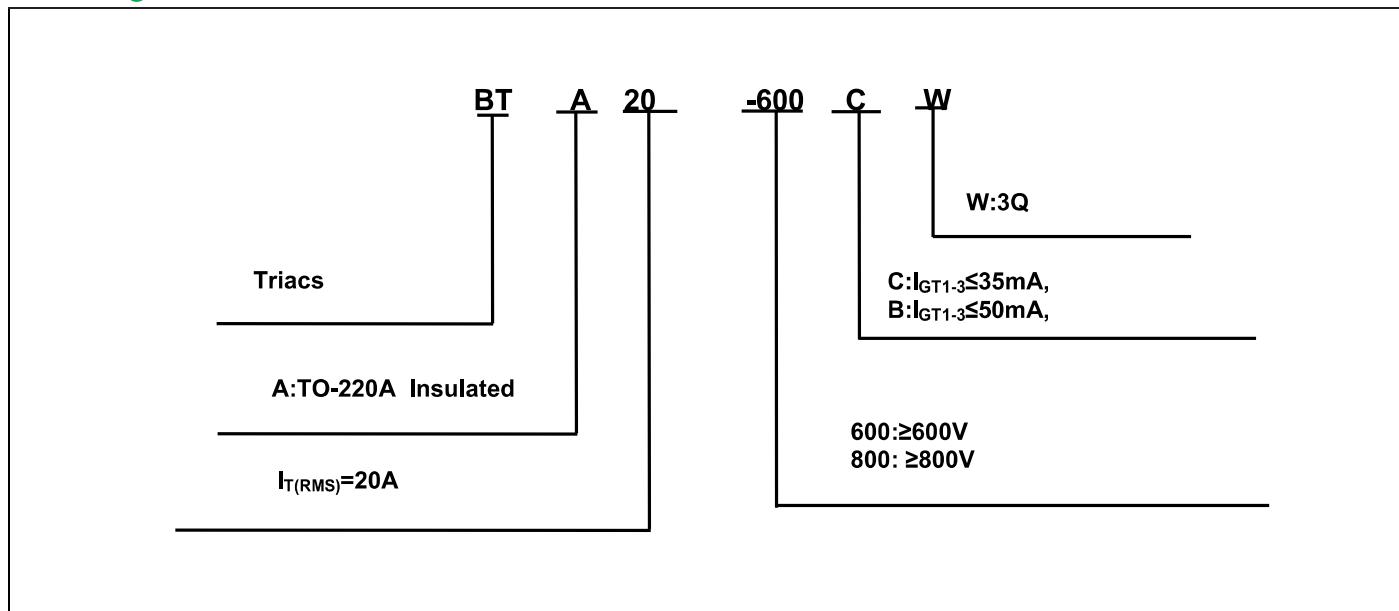
STATIC CHARACTERISTICS

Forward "on" voltage	V _{TM}	I _{TM} =28A, tp=380us, Fig.4	≤1.55 V	
Repetitive Peak Off-State Current	I _{DRM}	V _D =V _{DRM} V _R =V _{RRM}	T _j =25°C	≤5 uA
Repetitive Peak Reverse Current	I _{RRM}		T _j =125°C	≤1 mA

THERMAL RESISTANCES

Thermal resistance	R _{th(j-c)}	Junction to case	TYP.	2.1	°C/W
	R _{th(j-a)}	Junction to ambient	TYP.	60	°C/W

Ordering Information



Typical Characteristics

FIG1 Maximum power dissipation versus RMS on-state current

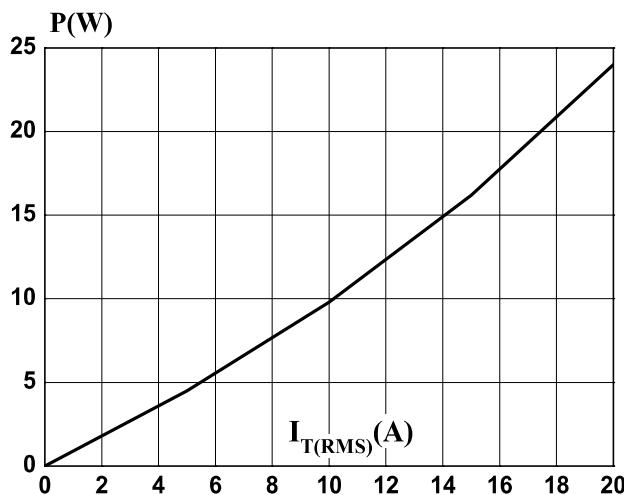


FIG3 Surge peak on-state current versus number of cycles

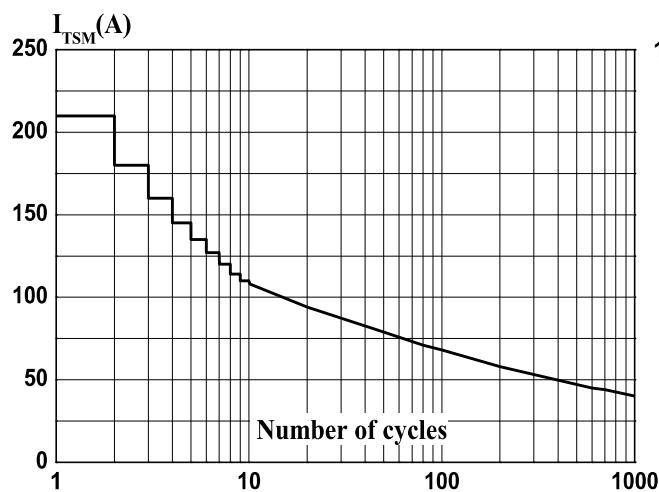


FIG5 Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of $\frac{dI}{dt}$ ($\frac{dI}{dt} < 100\text{A}/\mu\text{s}$)

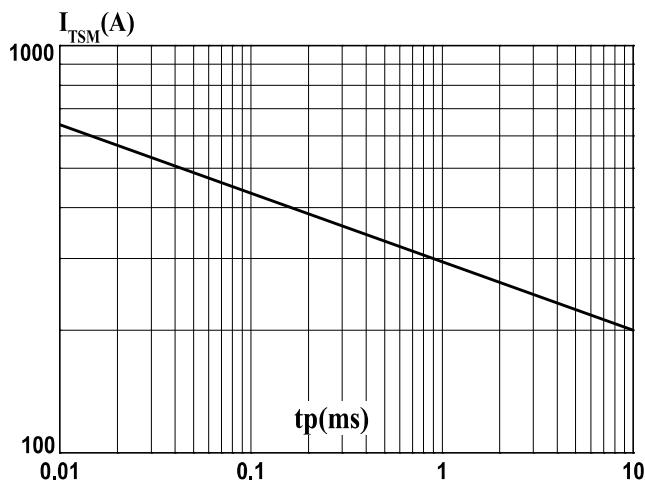


FIG2 RMS on-state current versus case temperature

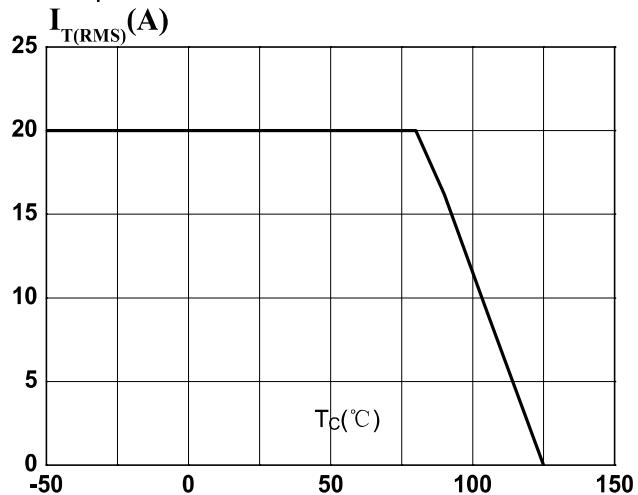


FIG4 On-state characteristics (maximum values)

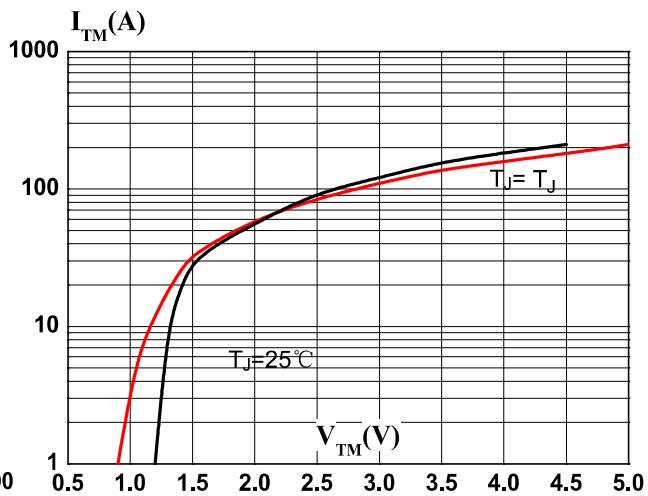
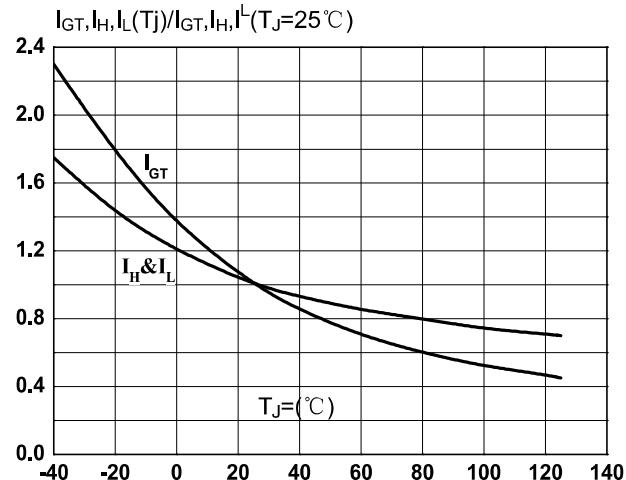
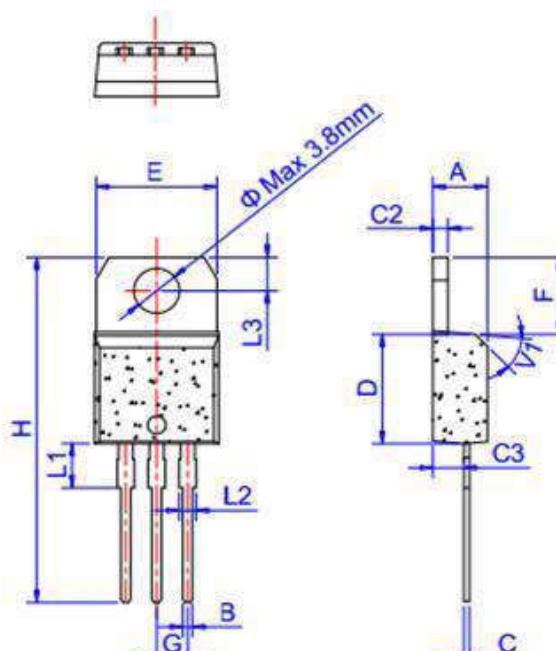


FIG6 Relative variations of gate trigger current, holding current and latching current versus junction temperature



Package Information

TO-220A(Ins)



The technical drawing illustrates the physical dimensions of the TO-220A Insulated package. It features a top view of the package body and two side views showing the lead configuration. Dimension lines are labeled with letters A through V1, indicating specific measurements for height, width, lead spacing, and lead thickness.

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.55		6.95	0.258		0.274
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

单击下面可查看定价，库存，交付和生命周期等信息

[>>YFW\(佑风微\)](#)